# BLA8H0910L-500; BLA8H0910LS-500

**Power LDMOS transistor** 

**AMPLEON** 

Rev. 1 — 7 February 2017

**Product data sheet** 

### 1. Product profile

#### 1.1 General description

A 500 W LDMOS power transistor for avionics applications at frequencies from 900 MHz to 930 MHz.

The BLA8H0910L-500 and BLA8H0910LS-500 are designed for high-power CW applications and are assembled in high performance ceramic packages.

Table 1. Typical performance

RF performance at  $V_{DS}$  = 50 V;  $I_{Dq}$  = 90 mA in a class-AB application circuit.

| Test signal      | f     | V <sub>DS</sub> | $P_L$ | G <sub>p</sub> | $\eta_{D}$ |
|------------------|-------|-----------------|-------|----------------|------------|
|                  | (MHz) | (V)             | (W)   | (dB)           | (%)        |
| CW [1]           | 915   | 50              | 500   | 18             | 61         |
| CW pulsed [2][3] | 915   | 50              | 500   | 19.5           | 62.5       |

- [1]  $T_{case} = 65 \, ^{\circ}C$ .
- [2]  $T_{case} = 25 \, ^{\circ}C$ .
- [3]  $t_p = 100 \,\mu\text{s}; \, \delta = 10 \,\%.$

#### 1.2 Features and benefits

- High efficiency
- Easy power control
- Excellent ruggedness
- Integrated ESD protection
- Designed for broadband operation (900 MHz to 930 MHz)
- Internally input matched
- Compliant to Directive 2002/95/EC, regarding Restriction of Hazardous Substances (RoHS)

#### 1.3 Applications

Avionics applications in the 900 MHz to 930 MHz frequency range

### 2. Pinning information

Table 2. Pinning

| Pin       | Description      | Simplified outline | Graphic symbol  |
|-----------|------------------|--------------------|-----------------|
| BLA8H0910 | L-500 (SOT502A)  |                    |                 |
| 1         | drain            |                    |                 |
| 2         | gate             | 5 1 2              | 1<br>           |
| 3         | source [1]       |                    | 2 3<br>sym112   |
| BLA8H0910 | LS-500 (SOT502B) |                    |                 |
| 1         | drain            |                    |                 |
| 2         | gate             | 1   3              | 1<br>           |
| 3         | source [1]       | 2                  | 2 - 3<br>sym112 |

<sup>[1]</sup> Connected to flange.

### 3. Ordering information

Table 3. Ordering information

| Type number     | Package |  |         |  |
|-----------------|---------|--|---------|--|
|                 | Name    | Description  | Version |  |
| BLA8H0910L-500  | -       | flanged ceramic package; 2 mounting holes; 2 leads | SOT502A |  |
| BLA8H0910LS-500 | -       | earless flanged ceramic package; 2 leads           | SOT502B |  |

### 4. Limiting values

Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

| Symbol           | Parameter                | Min             | Max   | Unit |
|------------------|--------------------------|-----------------|-------|------|
| $V_{DS}$         | drain-source voltage     | -               | 114.5 | V    |
| $V_{GS}$         | gate-source voltage      | -6              | +11   | V    |
| T <sub>stg</sub> | storage temperature      | <del>-</del> 65 | +150  | °C   |
| Tj               | junction temperature [1] | -               | 225   | °C   |

<sup>[1]</sup> Continuous use at maximum temperature will affect the reliability, for details refer to the online MTF calculator.

#### 5. Thermal characteristics

Table 5. Thermal characteristics

| Symbol                  | Parameter                                | Conditions                          | Тур | Unit |
|-------------------------|--|-------------------------------------|-----|------|
| R <sub>th(j-case)</sub> | thermal resistance from junction to case | $T_{case}$ = 80 °C; $P_{L}$ = 500 W | 0.2 | K/W  |

BLA8H0910L-500\_0910LS-500

#### 6. Characteristics

Table 6. DC characteristics

 $T_i$  = 25 °C, unless otherwise specified.

| Symbol              | Parameter                        | Conditions   | Min   | Тур   | Max  | Unit |
|---------------------|----------------------------------|--|-------|-------|------|------|
| $V_{(BR)DSS}$       | drain-source breakdown voltage   | $V_{GS}$ = 0 V; $I_D$ = 4 mA                                       | 114.5 | -     | -    | V    |
| $V_{GS(th)}$        | gate-source threshold voltage    | V <sub>DS</sub> = 10 V; I <sub>D</sub> = 400 mA                    | 1.25  | 1.9   | 2.35 | V    |
| I <sub>DSS</sub>    | drain leakage current            | V <sub>GS</sub> = 0 V; V <sub>DS</sub> = 50 V                      | -     | -     | 2.8  | μΑ   |
| I <sub>DSX</sub>    | drain cut-off current            | $V_{GS} = V_{GS(th)} + 3.75 \text{ V};$<br>$V_{DS} = 10 \text{ V}$ | -     | 60    | -    | Α    |
| I <sub>GSS</sub>    | gate leakage current             | V <sub>GS</sub> = 11 V; V <sub>DS</sub> = 0 V                      | -     | -     | 280  | nA   |
| g <sub>fs</sub>     | forward transconductance         | V <sub>DS</sub> = 10 V; I <sub>D</sub> = 20 A                      | -     | 29    | -    | S    |
| R <sub>DS(on)</sub> | drain-source on-state resistance | $V_{GS} = V_{GS(th)} + 3.75 \text{ V};$<br>$I_D = 14 \text{ A}$    | -     | 0.078 | -    | Ω    |

#### Table 7. RF characteristics

Test signal: pulsed RF;  $t_p$  = 100  $\mu$ s;  $\delta$  = 10 %; f = 915 MHz; RF performance at  $V_{DS}$  = 50 V;  $I_{Da}$  = 90 mA;  $T_{case}$  = 25  $^{\circ}$ C; unless otherwise specified; in a class-AB production test circuit.

| Symbol     | Parameter         | Conditions             | Min | Тур  | Max | Unit |
|------------|-------------------|------------------------|-----|------|-----|------|
| Gp         | power gain        | P <sub>L</sub> = 500 W | 15  | 19   | -   | dB   |
| RLin       | input return loss | P <sub>L</sub> = 500 W | -   | -18  | -7  | dB   |
| $\eta_{D}$ | drain efficiency  | P <sub>L</sub> = 500 W | 59  | 63.5 | -   | %    |

### 7. Test information

#### 7.1 Ruggedness in class-AB operation

The BLA8H0910L-500 and BLA8H0910LS-500 are capable of withstanding a load mismatch corresponding to VSWR = 30 : 1 through all phases under the following conditions:  $V_{DS}$  = 50 V;  $I_{Dq}$  = 90 mA;  $P_{L}$  = 500 W (CW); f = 915 MHz.

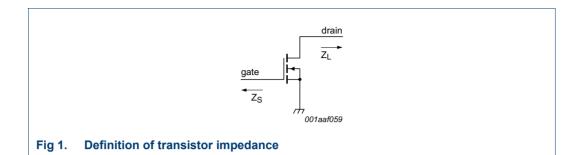
### 7.2 Impedance information

#### Table 8. Typical impedance

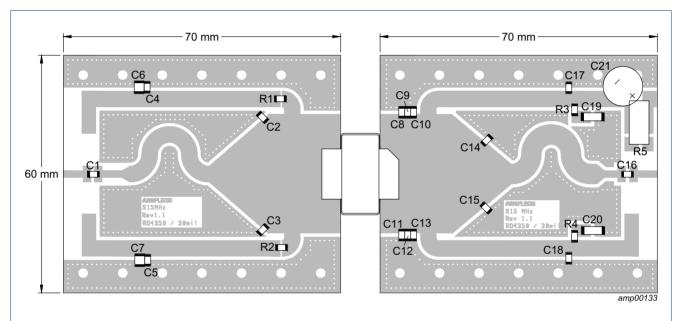
Measured load-pull  $Z_S$  and  $Z_L$  device impedances;  $I_{Dq}$  = 90 mA;  $V_{DS}$  = 50 V; typical values unless otherwise specified.

| f     | Z <sub>S</sub> [1] | Z <sub>L</sub> [1] |
|-------|--------------------|--------------------|
| (GHz) | (Ω)                | (Ω)                |
| 915   | 1.8 – 1.4j         | 0.6 + 0.35j        |

[1]  $Z_S$  and  $Z_L$  defined in Figure 1.



#### 7.3 Test circuit



Printed-Circuit Board (PCB): Rogers RO4350;  $\epsilon_r$  = 3.48; height = 0.762 mm; thickness copper plating = 35  $\mu$ m. See Table 9 for a list of components.

Fig 2. Component layout for application circuit

Table 9. List of components

See Figure 2 for component layout.

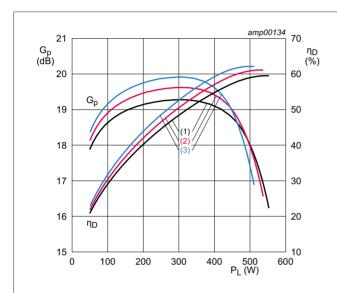
| Component         | Description                       | Value         | Remarks                    |
|-------------------|-----------------------------------|---------------|----------------------------|
| C1, C16           | multilayer ceramic chip capacitor | 470 pF        | ATC 800B                   |
| C2, C3            | multilayer ceramic chip capacitor | 2.4 pF        | ATC 800B                   |
| C4, C5, C17, C18  | multilayer ceramic chip capacitor | 100 pF        | ATC 800B                   |
| C6, C7            | multilayer ceramic chip capacitor | 4.7 μF, 50 V  | Murata: GRM32ER71H475KA88L |
| C8, C11           | multilayer ceramic chip capacitor | 5.6 pF        | ATC 800B                   |
| C9, C10, C12, C13 | multilayer ceramic chip capacitor | 4.7 pF        | ATC 800B                   |
| C14, C15          | multilayer ceramic chip capacitor | 0.9 pF        | ATC 800B                   |
| C19, C20          | multilayer ceramic chip capacitor | 4.7 μF, 100 V | TDK: C5750X7R2A475KT/A     |
| C21               | electrolytic capacitor            | 470 μF, 63 V  |                            |

Table 9. List of components ...continued

See Figure 2 for component layout.

| Component | Description    | Value  | Remarks                |
|-----------|----------------|--------|------------------------|
| R1, R2    | resistor       | 10 Ω   | SMD1206                |
| R3, R4    | resistor       | 3 Ω    | SMD1206                |
| R5        | shunt resistor | 0.01 Ω | Ohmite: FC4L110R010FER |

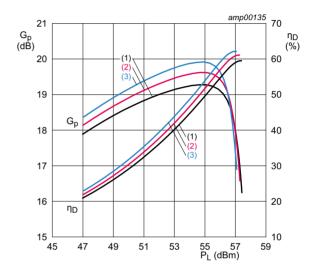
#### 7.4 Graphical data



 $V_{DS} = 50 \text{ V}; I_{Dq} = 90 \text{ mA}.$ 

- (1) f = 902 MHz
- (2) f = 915 MHz
- (3) f = 928 MHz

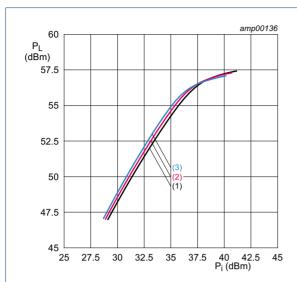
Fig 3. Power gain and drain efficiency as function of output power; typical values



 $V_{DS}$  = 50 V;  $I_{Dq}$  = 90 mA.

- (1) f = 902 MHz
- (2) f = 915 MHz
- (3) f = 928 MHz

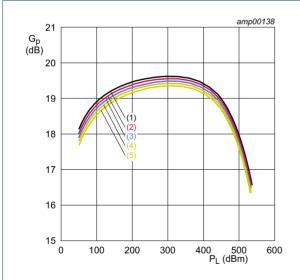
Fig 4. Power gain and drain efficiency as function of output power; typical values



 $V_{DS}$  = 50 V;  $I_{Dq}$  = 90 mA.

- (1) f = 902 MHz
- (2) f = 915 MHz
- (3) f = 928 MHz

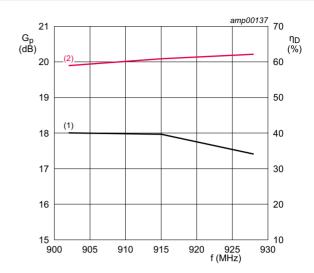
Fig 5. Output power as a function of input power; typical values



 $V_{DS} = 50 \text{ V}$ ; f = 915 MHz.

- (1)  $I_{Dq} = 90 \text{ mA}$
- (2)  $I_{Dq} = 80 \text{ mA}$
- (3)  $I_{Dq} = 70 \text{ mA}$
- (4)  $I_{Dq} = 60 \text{ mA}$
- (5)  $I_{Dq} = 50 \text{ mA}$

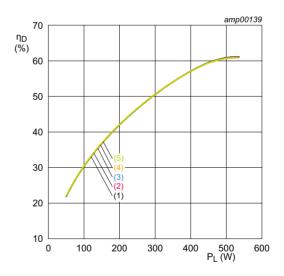
Fig 7. Power gain as a function of output power; typical values



 $V_{DS} = 50 \text{ V}; I_{Dq} = 90 \text{ mA}; P_L = 500 \text{ W}.$ 

- (1) G<sub>p</sub>
- (2) η<sub>D</sub>

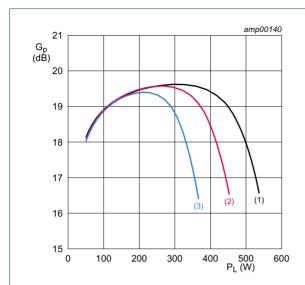
Fig 6. Power gain and drain efficiency as a function of frequency; typical values



 $V_{DS} = 50 \text{ V}; f = 915 \text{ MHz}.$ 

- (1)  $I_{Dq} = 90 \text{ mA}$
- (2)  $I_{Dq} = 80 \text{ mA}$
- (3)  $I_{Dq} = 70 \text{ mA}$
- (4)  $I_{Dq} = 60 \text{ mA}$
- (5)  $I_{Dq} = 50 \text{ mA}$

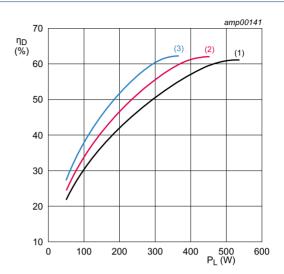
Fig 8. Drain efficiency as a function of output power; typical values



 $I_{Dq} = 90 \text{ mA}$ ; f = 915 MHz.

- (1)  $V_{DS} = 50 \text{ V}$
- (2)  $V_{DS} = 45 \text{ V}$
- (3)  $V_{DS} = 40 \text{ V}$

Fig 9. Power gain as a function of output power; typical values



 $I_{Dq} = 90 \text{ mA}$ ; f = 915 MHz.

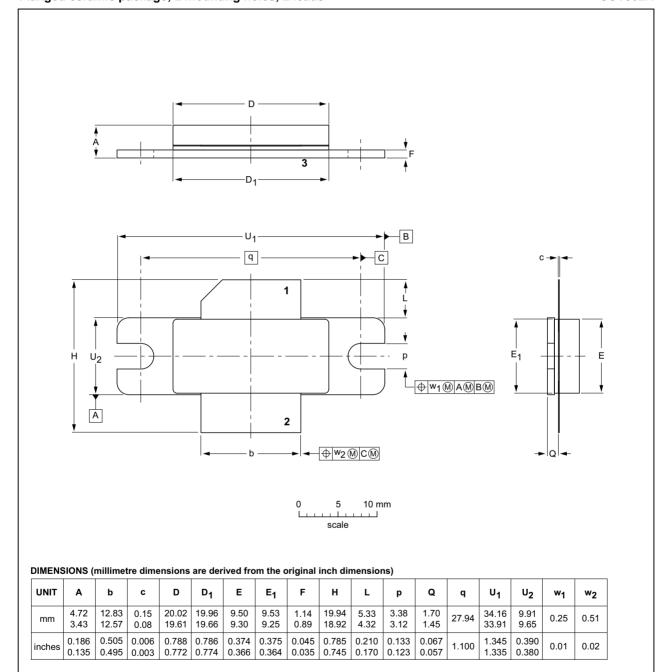
- (1)  $V_{DS} = 50 \text{ V}$
- (2)  $V_{DS} = 45 \text{ V}$
- (3)  $V_{DS} = 40 \text{ V}$

Fig 10. Drain efficiency as a function of output power; typical values

### 8. Package outline

#### Flanged ceramic package; 2 mounting holes; 2 leads

SOT502A



OUTLINE VERSION IEC JEDEC JEITA

SOT502A

REFERENCES

EUROPEAN PROJECTION

ISSUE DATE

-03-01-1012-05-02

Fig 11. Package outline SOT502A

#### Earless flanged ceramic package; 2 leads

#### SOT502B

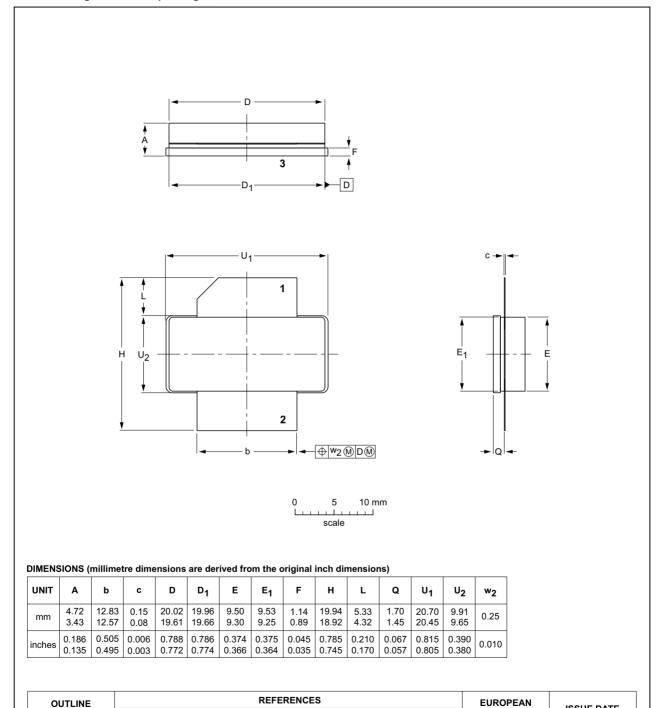


Fig 12. Package outline SOT502B

IEC

**JEDEC** 

VERSION

SOT502B

**JEITA** 

**ISSUE DATE** 

07-05-09

12-05-02

**PROJECTION** 

### 9. Handling information

#### **CAUTION**



This device is sensitive to ElectroStatic Discharge (ESD). Observe precautions for handling electrostatic sensitive devices.

Such precautions are described in the ANSI/ESD S20.20, IEC/ST 61340-5, JESD625-A or equivalent standards.

Table 10. ESD sensitivity

| ESD model  | Class  |
|--|--------|
| Charged Device Model (CDM); According to ANSI/ESDA/JEDEC standard JS-002 | C1 [1] |
| Human Body Model (HBM); According to ANSI/ESDA/JEDEC standard JS-001     | 2 [2]  |

- [1] CDM classification C1 is granted to any part that passes after exposure to an ESD pulse of 250 V, but fails after exposure to an ESD pulse of 500 V.
- [2] HBM classification 2 is granted to any part that passes after exposure to an ESD pulse of 2000 V, but fails after exposure to an ESD pulse of 4000 V.

#### 10. Abbreviations

Table 11. Abbreviations

| Acronym | Description                                  |
|---------|--|
| CW      | Continuous wave                              |
| ESD     | ElectroStatic Discharge                      |
| LDMOS   | Laterally Diffused Metal-Oxide Semiconductor |
| MTF     | Median Time to Failure                       |
| SMD     | Surface Mounted Device                       |
| VSWR    | Voltage Standing-Wave Ratio                  |

### 11. Revision history

Table 12. Revision history

| Document ID                   | Release date | Data sheet status  | Change notice | Supersedes |
|-------------------------------|--------------|--------------------|---------------|------------|
| BLA8H0910L-500_0910LS-500 v.1 | 20170207     | Product data sheet | -             | -          |

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|--------------------------------|-------------------|---|
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## BLA8H0910L(S)-500

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## **AMPLEON**

# BLA8H0910L(S)-500

**Power LDMOS transistor** 

### 14. Contents

| 1    | Product profile                  | . 1 |
|------|----------------------------------|-----|
| 1.1  | General description              |     |
| 1.2  | Features and benefits            |     |
| 1.3  | Applications                     | . 1 |
| 2    | Pinning information              | . 2 |
| 3    | Ordering information             | . 2 |
| 4    | Limiting values                  | . 2 |
| 5    | Thermal characteristics          | . 2 |
| 6    | Characteristics                  | . 3 |
| 7    | Test information                 | . 3 |
| 7.1  | Ruggedness in class-AB operation | . 3 |
| 7.2  | Impedance information            | . 3 |
| 7.3  | Test circuit                     | . 4 |
| 7.4  | Graphical data                   | . 5 |
| 8    | Package outline                  | . 8 |
| 9    | Handling information             | 10  |
| 10   | Abbreviations                    | 10  |
| 11   | Revision history                 | 10  |
| 12   | Legal information                | 11  |
| 12.1 | Data sheet status                |     |
| 12.2 | Definitions                      | 11  |
| 12.3 | Disclaimers                      | 11  |
| 12.4 | Trademarks                       | 12  |
| 13   | Contact information              | 12  |
| 14   | Contents                         | 13  |

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